Single 2-Input NAND Gate

The NL17SZ00 is a single 2-input NAND Gate in two tiny footprint packages. The device performs much as LCX multi-gate products in speed and drive.

Features

- Tiny SOT-353 and SOT-553 Packages
- 2.7 ns T_{PD} at 5 V (typ)
- Source/Sink 24 mA at 3.0 V
- Over–Voltage Tolerant Inputs
- Pin For Pin with NC7SZ00P5X, TC7SZ00FU and TC7SZ00AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Pb–Free Packages are Available

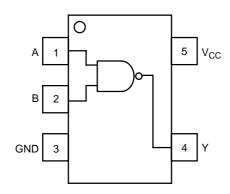


Figure 1. Pinout (Top View)

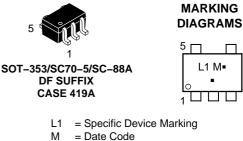


Figure 2. Logic Symbol



ON Semiconductor®

http://onsemi.com



= Date Code
 = Pb-Free Package

(Note: Microdot may be in either location)

⁵ 1 SOT-553 XV5 SUFFIX CASE 463B



L1 = Specific Device Marking M = Date Code

PIN ASSIGNMENT

Pin	Function
1	А
2	В
3	GND
4	Y
5	V _{CC}

FUNCTION TABLE

Inp	Input				
A	В	Y			
L	L	н			
L	Н	н			
н	L	н			
Н	Н	L			

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V	
V _{IN}	DC Input Voltage	-0.5 to +7.0	V	
V _{OUT}	DC Output Voltage		-0.5 to to V _{CC} + 0.5	V
Ι _{ΙΚ}	DC Input Diode Current	-50	mA	
I _{OK}	DC Output Diode Current	-50	mA	
I _{OUT}	DC Output Sink Current	±50	mA	
I _{CC}	DC Supply Current per Supply Pin	±100	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for 1	260	°C	
TJ	Junction Temperature Under Bias		+ 150	°C
θ_{JA}	Thermal Resistance	SOT–353 (Note 1) SOT–553	350 496	°C/W
PD	Power Dissipation in Still Air at 85°C	SOT-353 SOT-553	186 135	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD		luman Body Model (Note 2) Machine Model (Note 3) rged Device Model (Note 4)	Class Z Class A N/A	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.

3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.

4. Tested to JESD22–C101–A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	DC Supply Voltage	1.65	5.5	V	
V _{IN}	DC Input Voltage	0	5.5	V	
V _{OUT}	DC Output Voltage	0	V _{CC} + 0.5	V	
T _A	Operating Temperature Range	- 40	+ 85	°C	
t _r , t _f	Input Rise and Fall Time	$V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

			V _{cc}	Т	A = 25°	С	−40°C ≤	$T_A \leq 85^{\circ}C$	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V _{CC} 0.7 V _{CC}			0.75 V _{CC} 0.7 V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V _{CC} 0.3 V _{CC}		0.25 V _{CC} 0.3 V _{CC}	V
V _{OH}	High–Level Output Voltage V _{IN} = V _{IL} or V _{IH}	$I_{OH} = 100 \ \mu A$ $I_{OH} = -3 \ m A$ $I_{OH} = -8 \ m A$ $I_{OH} = -12 \ m A$ $I_{OH} = -16 \ m A$ $I_{OH} = -24 \ m A$ $I_{OH} = -32 \ m A$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V _{CC} - 0.1 1.55 1.9 2.2 2.4 2.3 3.8	V _{CC} 1.65 2.1 2.4 2.7 2.5 4.0		V _{CC} - 0.1 1.55 1.9 2.2 2.4 2.3 3.8		V
V _{OL}	Low–Level Output Voltage V _{IN} = V _{IH} or V _{OH}	$I_{OL} = 100 \ \mu A$ $I_{OL} = 3 \ m A$ $I_{OL} = 8 \ m A$ $I_{OL} = 12 \ m A$ $I_{OL} = 16 \ m A$ $I_{OL} = 24 \ m A$ $I_{OL} = 32 \ m A$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.20 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55		0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I _{IN}	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	0 to 5.5			±0.1		±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1		10	μΑ

AC ELECTRICAL CHARACTERISTICS t_{R} = t_{F} = 3.0 ns

			V _{CC}	$T_A = 25^{\circ}C$;	-40°C ≤ 1		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Мах	Unit
t _{PLH}	t _{PLH} Propagation Delay	$R_L = 1 M\Omega$, $C_L = 15 pF$	1.65	2.0	5.4	11.4	2.0	12	ns
t _{PHL}	(Figure 3 and 4)	$R_L = 1 M\Omega, C_L = 15 pF$	1.8	2.0	4.5	9.5	2.0	10.0	
		$R_L = 1 M\Omega$, $C_L = 15 pF$	2.5 to 0.2	0.8	3.0	6.5	0.8	7.0	
		$R_L = 1 M\Omega$, $C_L = 15 pF$	3.3 ± 0.3	0.5	2.4	4.5	0.5	4.7	
		$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		1.5	2.4	5.0	1.5	5.2	
		$R_L = 1 M\Omega, C_L = 15 pF$	5.0 ± 0.5	0.5	2.0	3.9	0.5	4.1	
		$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		0.8	2.4	4.3	0.8	4.5	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Parameter Condition					
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC}	>4	pF			
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	25	pF			
	(Note 5)	10 MHz, V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC}	30				

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

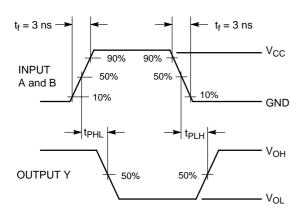
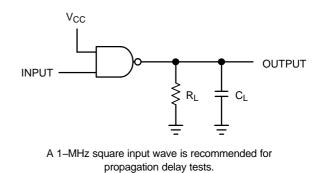


Figure 3. Switching Waveform





DEVICE ORDERING INFORMATION

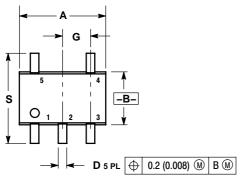
		Device Nomenclature							
Device Order Number	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape and Reel Suffix	Package Type	Tape and Reel Size †
NL17SZ00DFT2	NL	1	7	SZ	00	DF	T2	SOT-353	178 mm, 3000 Units
NL17SZ00DFT2G	NL	1	7	SZ	00	DF	T2	SOT-353 (Pb-Free)	178 mm, 3000 Units
NL17SZ00XV5T2	NL	1	7	SZ	00	XV5	T2	SOT-553*	178 mm 4000 units
NL17SZ00XV5T2G	NL	1	7	SZ	00	XV5	T2	SOT-553*	178 mm 4000 units

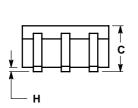
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *All Devices in Package SOT553 are Inherently Pb–Free.

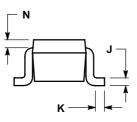
NL17SZ00

PACKAGE DIMENSIONS

SOT-353 (SC-88A, SC-70) **DF SUFFIX** CASE 419A-02 **ISSUE J**







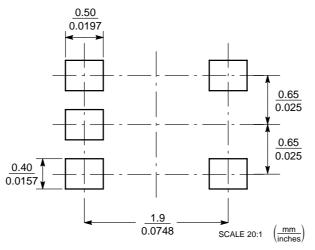
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.

- CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

<u> </u>				ETERO
		HES		ETERS
DIM	MIN MAX		MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
Ν	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

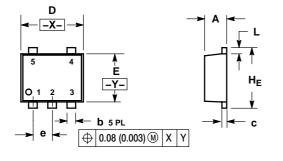
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOT-553 **XV5 SUFFIX** CASE 463B-01 ISSUE B



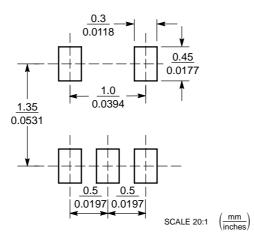
NOTES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF DATE MATERIAL 1. 2

3.

THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.50	0.55	0.60	0.020	0.022	0.024	
b	0.17	0.22	0.27	0.007	0.009	0.011	
С	0.08	0.13	0.18	0.003	0.005	0.007	
D	1.50	1.60	1.70	0.059	0.063	0.067	
Е	1.10	1.20	1.30	0.043	0.047	0.051	
е	0.50 BSC			0.020 BSC			
L	0.10	0.20	0.30	0.004	0.008	0.012	
HE	1.50	1.60	1.70	0.059	0.063	0.067	

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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